Diffused morphotropic phase boundary in relaxor-PbTiO3 crystals: High piezoelectricity with improved thermal stability

Gang Liu
Lingping Kong
Qingyang Hu
Shujun Zhang

University of Wollongong, shujun@uow.edu.au

Follow this and additional works at: https://ro.uow.edu.au/aiimpapers

Part of the Engineering Commons, and the Physical Sciences and Mathematics Commons

Recommended Citation
https://ro.uow.edu.au/aiimpapers/4252
Diffused morphotropic phase boundary in relaxor-PbTiO3 crystals: High piezoelectricity with improved thermal stability

Abstract
© 2020 Author(s). Solid solution ferroelectrics are the most widely used piezoelectric material for numerous electromechanical applications, including sensors, actuators, and transducers. A milestone in ferroelectric research is the discovery of the morphotropic phase boundary that was first reported in Pb(ZrxTi1-x)O3, which has been extensively solicited to improve the performance of various solid solution ferroelectrics, including those having the highest piezoelectricity known today. However, due to the inherent correlation between phase transition and thermodynamic imbalance, the efforts of building the phase boundary encounter the challenge that high performance materials are generally accompanied by property instability. Here, we report a comprehensive study on the crystalline symmetry and polar nano-regions in relaxor-PbTiO3 crystals by synchrotron measurements and property characterizations. In contrast to the common belief that the morphotropic phase boundary is a narrow composition region, the morphotropic phase boundary in ternary Pb(In1/2Nb1/2)O3-Pb(Mg1/3Nb2/3)O3-PbTiO3 is demonstrated as an extensive region covering at least 9% of the PbTiO3 content. Such a diffused morphotropic phase boundary is associated with the intensive interaction of polar nano-regions, leading to high piezoelectricity (>1500 pC/N) with greatly improved thermal stability, where the piezoelectric variation is ~90% over the temperature range of 273-373 K, which is about a factor of 3 lower compared to its binary counterpart Pb(Mg1/3Nb2/3)O3-PbTiO3. This work sheds light on the fundamental understanding of nanoscale inhomogeneity and macroscopic symmetry in relaxor-PbTiO3, and successfully interlinks the structure and properties in complex solid solutions. The existence of a diffused morphotropic phase boundary is also expected to benefit other ferroic systems beyond ferroelectrics, such as ferromagnetic and multiferroic materials.

Disciplines
Engineering | Physical Sciences and Mathematics

Publication Details

This journal article is available at Research Online: https://ro.uow.edu.au/aiimpapers/4252
Diffused morphotropic phase boundary in relaxor-PbTiO$_3$ crystals: High piezoelectricity with improved thermal stability

Cite as: Appl. Phys. Rev. 7, 021405 (2020); https://doi.org/10.1063/5.0004324
Submitted: 10 February 2020 . Accepted: 14 April 2020 . Published Online: 07 May 2020

Gang Liu, Lingping Kong, Qingyang Hu, and Shujun Zhang

Collected Articles You May Be Interested In

Genesis and evolution of extended defects: The role of evolving interface instabilities in cubic SiC
Applied Physics Reviews 7, 021402 (2020); https://doi.org/10.1063/1.5132300

Identification of light sources using machine learning
Applied Physics Reviews 7, 021404 (2020); https://doi.org/10.1063/1.5133846

Broadband enhancement of on-chip single-photon extraction via tilted hyperbolic metamaterials
Applied Physics Reviews 7, 021403 (2020); https://doi.org/10.1063/1.5141275
Diffused morphotropic phase boundary in relaxor-PbTiO$_3$ crystals: High piezoelectricity with improved thermal stability

Gang Liu, Lingping Kong, Qingyang Hu, and Shujun Zhang

AFFILIATIONS
1 Center for High Pressure Science and Technology Advanced Research, Shanghai 201203, China
2 Institute for Superconducting and Electronic Materials, Australian Institute for Innovative Materials, University of Wollongong, NSW 2500, Australia

ABSTRACT

Solid solution ferroelectrics are the most widely used piezoelectric material for numerous electromechanical applications, including sensors, actuators, and transducers. A milestone in ferroelectric research is the discovery of the morphotropic phase boundary that was first reported in Pb(ZrxTi1-x)O3, which has been extensively solicited to improve the performance of various solid solution ferroelectrics, including those having the highest piezoelectricity known today. However, due to the inherent correlation between phase transition and thermodynamic imbalance, the efforts of building the phase boundary encounter the challenge that high performance materials are generally accompanied by property instability. Here, we report a comprehensive study on the crystalline symmetry and polar nano-regions in relaxor-PbTiO$_3$ crystals by synchrotron measurements and property characterizations. In contrast to the common belief that the morphotropic phase boundary is a narrow composition region, the morphotropic phase boundary in ternary Pb(In$_{1/2}$Nb$_{1/2}$)O$_3$-Pb(Mg$_{1/3}$Nb$_{2/3}$)O$_3$-PbTiO$_3$ is demonstrated as an extensive region covering at least 9% of the PbTiO$_3$ content. Such a diffused morphotropic phase boundary is associated with the intensive interaction of polar nano-regions, leading to high piezoelectricity (>1500 pC/N) with greatly improved thermal stability, where the piezoelectric variation is ~90% over the temperature range of 273–373 K, which is about a factor of 3 lower compared to its binary counterpart Pb(Mg$_{1/3}$Nb$_{2/3}$)O$_3$-PbTiO$_3$. This work sheds light on the fundamental understanding of nanoscale inhomogeneity and macroscopic symmetry in relaxor-PbTiO$_3$, and successfully interlinks the structure and properties in complex solid solutions. The existence of a diffused morphotropic phase boundary is also expected to benefit other ferroic systems beyond ferroelectrics, such as ferromagnetic and multiferroic materials.

Published under license by AIP Publishing. https://doi.org/10.1063/5.0004324

I. INTRODUCTION

The concept of morphotropic phase boundary (MPB) was developed to demonstrate the composition dependent ferroelectric-ferroelectric phase transitions, which is the mainstay approach to improve the performance of ferroelectric solid solutions and guides the design of new piezoelectric materials. 1-4 The MPB was initially reported to be a linear boundary in Pb(Zr$_{x}$Ti$_{1-x}$)O$_3$ (PZT). 5 separating rhombohedral and tetragonal phases, which possess similar free energies. In the late 1990s, the monoclinic phases were observed in Pb(Zr$_{x}$Ti$_{1-x}$)$_3$O$_9$ by synchrotron XRD. 6 These low-symmetry monoclinic phases were thought to be the bridging phases connecting rhombohedral and tetragonal structures, 7,8 thus expanding the MPB region in the composition-temperature phase diagram, further flattening the free energy profile of the polarization rotation between rhombohedral and tetragonal phases, 9 and being responsible for the enhanced piezoelectricity. Therefore, it is generally accepted that the MPB is a phase coexistence region, where the composition width of MPB is crucial for functionality improvement. The MPB concept is particularly important also because it has been expanded to ferromagnetics, multiferroics, and functional alloys, all of which describe the unique properties due to the energy competition between two parent crystal phases, 10-12 further confirming the strong correlation between high functionalities and structural instability.

Analogous to ferroelectric-ferroelectric MPB, obvious piezoelectric enhancement has also been demonstrated as the temperature approaches the ferroelectric-ferroelectric phase transition, where the
crystallographic structure becomes more cubic-like and the free-energy profile is globally isotropic. Thus, an easier polarization extension occurs along the direction linking the paraelectric phase (cubic) and ferroelectric phases. As an example, a high piezoelectric coefficient, ~620 pC/N, has been reported in Ba(Ti0.8Zr0.2)O3-(Ba0.7Ca0.3)TiO3 (BZT-BCT) lead-free piezoceramics with a relatively low Curie temperature of ~100 °C, which is associated with the critical triple phases. It should be noted that high piezoelectric coefficients in temperature-driven phase transition regions are rarely useful because of the inherent instabilities.

To further improve the piezoelectric activity of ferroelectric materials, two general strategies have been employed, including the design of ferroelectric solid solutions with MPB composition and a shift in the polymorphic phase transition near room temperature [Fig. 1(a)]. Due to the inevitable phase transitions and/or decreased Curie temperature, these efforts encounter the challenge that high-performance materials are generally accompanied by instabilities [Figs. 1(b) and 1(c)], including the considerable loss of thermal resistance ability, and thus exhibit significant variation in properties as a function of temperature. Therefore, it is desired to re-scrutinize the properties of the solid solution ferroelectrics to gain a fundamental understanding of phase transition boundary, which is expected to broaden the usage temperature range while retaining, if not improving, the piezoelectric merits of solid solution ferroelectrics with MPB composition.

The most recently proposed approach to increase piezoelectricity in ferroelectrics is to engineer the local structure heterogeneity, which induces the greatly flattened local free-energy profile by interfacial energy competition. The local structure heterogeneity, or polar nanoregions, was first reported to exist in complex perovskites with the chemical formula of Pb(B',B'')O3, named as relaxor ferroelectrics, where B' and B'' are low and high valence cations, respectively. These relaxor ferroelectrics have frequency-dispersed dielectric properties with diffused phase transition characteristics. Then, it was discovered that by creating a solid solution with normal ferroelectrics and a relaxor end member, the piezoelectric activity can be greatly improved with peak values at the MPB over a broad composition range, demonstrating a great potential for commercial applications. This phenomenon was empirically employed in Pb(Ni1/3Nb2/3)O3-Pb(Zr0.3Ti0.7)O3 (PNN-PZT) solid solution,20–23 where the coexistence of the rhombohedral and tetragonal phases over a composition range of 0.3PNN-0.7PZT and 0.1PNN-0.9PZT accounts for the high dielectric constant,24 thus suggesting the crucial role of a wide MPB in property improvement of ferroelectric ceramics. It is worth noting that the studied PNN-PZT samples are polycrystalline ceramics, in which the compositional homogeneity, sample processing conditions, and particle size will significantly affect the width of MPB.21–27 In addition, we should note that the detectable width of a MPB depends on the compositional/phase resolution of the characterization tools, and in this context, the employed in-house XRD cannot provide high enough resolution for accurate structural analysis. Therefore, it is essential to study single crystal systems with a high resolution XRD technique in order to comprehensively understand the role of the wide MPB region in solid solution ferroelectrics and its impact on macroscopic properties.

In the early 1970s, solid solution ferroelectric single crystal Pb(Zn1/3Nb2/3)O3-PbTiO3 was reported, followed by the successful growth of various relaxor-PbTiO3 single crystals with ultrahigh piezoelectric coefficients and electromechanical coupling factors in the 1980s through the 1990s.23–52 The cornerstone ferroelectric research on relaxor-PbTiO3 perovskite solid solution with MPB compositions has been the driving force for emerging electromechanical applications, with the latest piezoelectric activity reaching over 4000 pC/N in Sm-doped Pb(Mg1/3Nb2/3)O3-PbTiO3 (PMN-PT) single crystals.28 The actively studied relaxor-PT crystals possess a narrow MPB region with 2–3 mol. % PbTiO3 consisting of different ferroelectric phases on both sides.34,35

In this work, we conducted a detailed structural analysis on the Pb(In1/3Nb2/3)O3-Pb(Mg1/3Nb2/3)O3-PbTiO3 (PIN-PMN-PT) ternary crystals and compared it to PMN-PT binary crystals using ultrahigh-resolution synchrotron-based characterizations. We discovered that the monoclinic crystallographic symmetry highly diffuses into both the rhombohedral and tetragonal phases with an extremely extended

![Graph](image-url)
span of at least 9 mol. % PT contents in the ternary solid solution. Our high-resolution synchrotron-based experiments, on the one hand, provided a solid proof for the diffused MPB in PIN-PMN-PT crystals, which quantitatively determined the width of the MPB region. Such a diffused MPB motivated us to replot the composition-temperature phase diagram and answered the question why both ultrahigh piezoelectricity and good thermal stability can be achieved simultaneously in the relaxor ferroelectric system. On the other hand, the obtained structural information, along with the detailed characterizations of dielectric/piezoelectric behavior, clarified the underlying mechanism linking the local structure at the nanoscale, the crystallographic symmetry, and the macroscopic properties in relaxor-PT crystals, which also echoes previous observations in PZT-based ceramics.

II. RESULTS AND DISCUSSION
A. Crystal samples and functional characterizations

High-quality [001] grown PIN-PMN-PT crystals with a diameter of 100 mm were successfully grown at TRS Technologies [the schematic figure is given in Fig. 2(a), while the color change represents the Ti segregation]. The samples used in this study were cut along the growth direction with different PT contents, where both rhombohedral-like (low PT content) and tetragonal-like (high PT content) ternary crystals [i.e., 0.26PIN-0.47PMN-0.27PT, 0.26PIN-0.44PMN-0.30PT, 0.26PIN-0.42PMN-0.32PT, and 0.26PIN-0.38PMN-0.36PT crystals (shortened to PINMT27, PINMT30, PINMT32, and PINMT36, respectively)] were considered. The quantitative compositions of various samples were further confirmed by synchrotron submicron x-ray fluorescence experiments conducted at beamline 2ID-D, Advanced Phonon Source (APS), Argonne National Laboratory (ANL). Their elemental composition (such as In and Ti) was detected, and relative percentages are given in Fig. 2(b).

Domain configurations in the PIN-PMN-PT single crystal samples were determined by the polar directions of crystal symmetry [Fig. 2(c)] and the poling process. By poling the crystals along different crystallographic directions, various artificial domain configurations can be formed (for details see Table S1 in the supplementary material), leading to very different piezoelectric, electromechanical, and loss properties. Thus, to fully characterize the material properties of the PIN-PMN-PT crystals, we poled the crystals along the [001] and [111] directions and studied their piezoelectric coefficients and electromechanical couplings [Figs. 2(d) and 2(e)]. As listed in Table S1, single domain configuration is established in [001] poled high-PT and [111] poled low-PT crystals, while [001] poled low-PT and [111] poled high-PT content crystals have 4 R and 3 T engineered-domain configurations, respectively. As shown in Figs. 2(d) and 2(e), PIN-PMN-PT possess comparable piezoelectric coefficients $d_{33}$ and electromechanical coupling $k_{33}$ to their PMN-PT binary counterpart. The ferroelectric-paraelectric phase transition temperatures observed in PIN-PMN-PT are particularly interesting, around 155 $^\circ$C–240 $^\circ$C, which are 30–65 $^\circ$C higher than the PMN-PT crystals with similar PT contents [Fig. 2(f)]. Together with their high coercive fields and enhanced field-induced phase transition level (see Fig. S1 in the supplementary material), the PIN-PMN-PT crystals promise a good candidate for broadened temperature usage range and drive field stability.

Several thermodynamic-based models, such as the instability of the structure phase at the MPB, ease of polarization rotation/extension, and critical phenomenon, have been proposed to understand the ultrahigh piezoelectric property of relaxor-PT crystals. However, these mechanisms fail to explain why PIN-PMN-PT exhibits comparable piezoelectricity but greatly enhanced thermal stability when compared with their binary counterpart, even though the ternary system possesses higher $T_c$ and $T_r$. Therefore, a comprehensive investigation and comparative analysis should be conducted on binary PMN-PT and ternary PIN-PMN-PT solid solution crystals.

To explore the origin of this interesting behavior, we first consider the intrinsic (piezoelectric lattice-deformation) and extrinsic (i.e., domain wall or phase boundary motions) contributions to the material properties. Figure 2(g) summarizes the loss behavior of the PIN-PMN-PT and PMN-PT crystals. The ternary PIN-PMN-PT crystals exhibit lower loss (higher mechanical quality factor $Q_{33}$ values) compared to their binary counterpart for both engineered-domain and single domain configurations. It has been generally accepted that the extrinsic domain wall motion plays a crucial role in loss behavior. Thus, we reasonably believe that the lower loss in PIN-PMN-PT is attributed to the decreased extrinsic contribution. Meanwhile, the extrinsic contribution to the piezoelectric activity of PIN-PMN-PT crystals should be lower than that of their binary counterpart, which is confirmed by the measurements of piezoelectric coefficients with single- and multi-domain configurations (Fig. S2 in the supplementary material). These observations demonstrate that the excellent dielectric/piezoelectric property, together with the high thermal stability in PIN-PMN-PT, should be an intrinsic characteristic.

B. Polar nanoregions (PNRs) and dielectric relaxation

For perovskite ferroelectrics, the piezoelectric coefficient $d_{33}$ can be described as:

$$d_{33} = 2Q_{33}P_s e_{33},$$  

where $Q_{33}$ is the electrostrictive coefficient, $P_s$ is the spontaneous polarization, and $e_{33}$ is the dielectric permittivity. Relaxor-PTs have lower electrostrictive coefficients and spontaneous polarization compared to those of ferroelectric Pb(Zr,Ti)$_2$O$_3$ (PZT), yet they possess much higher piezoelectric coefficients. Therefore, we can conclude that the high piezoelectric activity is attributed to the high dielectric permittivity ($\sim$5000–10000 for domain-engineered relaxor-PT crystals with MPB compositions). Such a high dielectric response in the relaxor-PT system is inherently associated with the most important characteristic in relaxor-based ferroelectrics, namely, the presence of PNRs. The contribution of PNRs to the dielectric/piezoelectric response has been quantitatively characterized to be over 50% according to the recent cryogenic experimental measurements and phase-field calculations. Therefore, it is necessary to investigate the behavior of PNRs in ternary PIN-PMN-PT crystals and explore the possible difference from their binary PMN-PT counterparts.

Figure 3(a) shows the temperature-dependent dielectric response of the unpoled crystals, from which one could observe that the ferroelectric-to-paraelectric phase transitions proceed gradually with temperature rather than sharply. Such a diffuseness characteristic is a feature of relaxor, leading to the deviation from the Curie-Weiss law, where the Burn temperatures ($T_B$) of around 167 $^\circ$C–256 $^\circ$C can be derived (Fig. S3 in the supplementary material). Below $T_B$, the deviations from the Curie-Weiss law were observed due to the existence of PNRs. Various theoretical approaches have been developed to describe
the relaxor behavior. The temperature-dependence of dielectric properties can be represented by a modified Curie-Weiss law as:

\[ \frac{1}{\varepsilon(T)} - \frac{1}{\varepsilon_m} = \frac{(T - T_m)^\gamma}{C}. \]  

Here \( \gamma \) and \( C \) are assumed to be constant, and \( 1 \leq \gamma \leq 2 \). The parameter \( \gamma \) gives information on the shape of the anomaly in paraelectric phase. When \( \gamma = 1 \), the ideal Curie-Weiss law is observed, which is the case for normal ferroelectrics, whereas \( \gamma = 2 \) corresponds to ideal relaxor, which has diffuse phase transition. The calculated \( \gamma \) values for the studied ternary crystals are in the range of 1.47~1.65, demonstrating considerable relaxor characteristics, which is inconsistent with the nature of solid solution formed by normal-ferroelectric and relaxor end-members. The \( \gamma \) parameter alone cannot represent the relaxor behavior since it only describes the slope shape of the dielectric as a function of temperature. The degree of diffuse phase transition is also related to the width of the dielectric anomaly over the same frequency range.
Thus, the values of $c$ parameter derived from Eq. (2) only suggest that there are considerable relaxor characteristics in PINMT, but cannot be simply used for a quantitative analysis and comparison. Figures 3(c) and S4 in the supplementary material show the low-temperature dielectric property of (001)-poled PINMT32 crystal. We quantitatively estimated that the contribution of PNRs to the room-temperature dielectric response is about 50%, roughly the same as those of binary crystals (50% for PMN-0.30PT).46

FIG. 3. Dielectric properties and relaxor behavior. (a) Temperature dependence of dielectric permittivity for unpoled PINMT27, PINMT30, PINMT32, and PINMT36 crystals, at 1 kHz. (b) log($1/c_1 - 1/c_{\infty}$) vs log($T - T_m$) curves at temperatures above $T_m$ at 1 kHz for PINMT27, PINMT30, PINMT32, and PINMT36. Here we employed unpoled samples to obtain the relaxor behavior without any poling effects. (c) Low-temperature dielectric property for [001]-poled PINMT32 at various frequencies, from which the contribution of PNRs to the dielectric responses can be estimated. (d)–(f) High-temperature dielectric property for unpoled PINMT27, PINMT30, and PMN-0.29PT crystals, measured at frequencies of 20, 50, 100, 500, 1k, 5k, 10k, 50k, 100k, 500k, and 1M Hz. (g) Vogel-Fulcher fitting results on the data shown in (d)–(f), from which the activation energy $E_a$ and static freezing temperature $T_{VF}$ can be obtained. (h) Summary of activation energy for various PMN, PMN-PT, and PIN-PMN-PT. Data are from refs. 59, 61, and 62, and this work. (i) $T_{VF}/T_m$ value as a function of frequency for PMN-PT and PIN-PMN-PT. Data are from Refs. 59 and 61 and this work.

dielectric property of (001)-poled PINMT32 crystal. We quantitatively estimated that the contribution of PNRs to the room-temperature dielectric response is about 50%, roughly the same as those of binary crystals (50% for PMN-0.30PT).46
It is clear that the dielectric and piezoelectric properties of relaxor-PT crystals are dominated by intrinsic contribution, where no obvious difference is observed in the magnitude of PNRs’ contributions between PIN-PMN-PT and PMN-PT crystals. However, the PNRs themselves exhibit significantly different behavior between binary and ternary crystals, which is revealed by our following dielectric measurements. Figures 3(d)–3(f) show the high-temperature dielectric properties of the studied ternary crystals, where the magnitude of the dielectric permittivity decreases while the dielectric maximum shifts to higher temperatures with increasing frequency, demonstrating a strong relaxor behavior. Of particular interest is that the ternary crystals exhibit a much higher “Tm shift” (shift of the dielectric maxima temperature with frequency over the range of 20 Hz to 1 MHz) than those of the PMN-PT crystals, at around 14 K vs 5 K.

The experimental data shown in Figs. 3(d)–3(f) can be well fitted by the Vogel-Fulcher relationship following Eq. (3):58

\[
f = f_0 \exp \left(-\frac{E_a}{(T_m - T_{VF})} \right),
\]

where \(T_{VF}\) is the static freezing temperature, which can be deemed as the permittivity maximum temperature at 0 Hz; \(E_a\) is the activation energy; \(f_0\) is the Debye frequency; and \(T_m\) is the temperature of the permittivity maximum, which is a reflection of the inability of the PNRs to follow the drive field with increasing frequency. The Vogel-Fulcher relationship was previously introduced to describe the magnetic relaxation in spin-glass systems and then applied to relaxor ferroelectrics to understand the polarization fluctuation. \(E_a\) represents the activation energy of polarization fluctuation in an isolated cluster arising from the development of short-range order, and a larger \(E_a\) suggests a stronger interaction between neighboring PNRs.59,60 The fitted results are given in Fig. 3(g), revealing that the relaxor behavior in rhombohedral crystals is analogous to a polar-glassy system. The fitted parameters \(E_a\) of the PIN-PMN-PT crystals are particularly significant, around 0.0387 eV for PINMT27 and 0.0331 eV for PINMT30 because they are much higher than that of 0.71PMN-0.29PT (0.0152 eV), demonstrating a stronger PNR interaction in ternary crystals. The analysis of the \(T_{VF}\) values derived by the Vogel-Fulcher relationship also confirms this behavior. Figure 3(h) summarizes the \(E_a\) and \(T_{VF}\) values for various crystals, showing that PIN-PMN-PT exhibits its higher \(E_a\) and \(T_{VF}\) values compared to its binary counterpart with similar PT content. Figure 3(i) shows the calculated ratios of \(T_{VF}/T_m\), which decrease with increasing frequency due to the considerable “Tm shift.” The magnitude of “Tm shift” is associated with the interactions between the PNRs and the development of local correlations, and \(T_{VF}/T_m\) is a semi-quantitative parameter to evaluate the interaction. Compared with binary crystals, lower \(T_{VF}/T_m\) was observed in PIN-PMN-PT crystals, again confirming the strong PNR interactions, from which a higher degree of deviation from classic ferroelectric behavior can be expected.

Therefore, considering their higher \(T_m\) shift, higher \(E_a\) and lower \(T_{VF}/T_m\) values, we can reasonably conclude that PIN-PMN-PT crystals exhibit more relaxor-like characteristics than PMN-PT crystals. This can be explained by the microstructure, where the B-site ordering in PIN-PMN-PT is weaker than PMN-PT as a result of the mixture of four heterovalent cations on the same crystallographic location. Therefore, it becomes much more difficult for PIN-PMN-PT to establish homogeneous polarization ordering but only short-range ordering between neighboring clusters. A larger amount of PNRs with smaller size will form,62,64 and it is unsurprising to observe stronger PNR interaction associated with enhanced relaxor features in ternary PIN-PMN-PT, which could provide information crucial to understanding the superior piezoelectricity in relaxor ferroelectrics.

C. Phase coexistence in PIN-PMN-PT solid solutions

It has been demonstrated that PNRs can significantly affect the structural properties of the relaxor ferroelectrics due to a strong interaction between the PNR and the propagation of acoustic phonons, from which phase instability will be induced and finally contribute to the ultrahigh piezoelectric response.65,66 Therefore, we are motivated to re-examine the microstructure of ternary PIN-PMN-PT crystals to explore their possible structural instability and hidden crystallographic symmetry, and provide a full picture of the phase diagram.

The structure of ferroelectric solid solutions with MPB composition is sensitive to many factors, including strain/stress, domain size, local cation ordering, and chemical inhomogeneity, which makes comprehending them fully challenging. Recent developments in synchrotron-based detection techniques have pushed the achievable spatial resolution and the sensitivity of diffraction, imaging, and spectroscopy to an unparalleled level, providing new insight into the structure-property relationship of ferroelectric solid solutions. Here, we conducted in situ synchrotron X-ray diffraction investigations at the 11BM station of Argonne National Laboratory with ultrahigh resolution and flux (Fig. S5 in the supplementary material) to comprehensively study the phase diagram of the PIN-PMN-PT system. The results help us to monitor the crucial MPB diffusion phenomenon.

The room temperature structures of the PIN-PMN-PT system are given in Figs. 4 and S6–S12 in the supplementary material. It has been reported that PINMT27 and PINMT30 possess a pure rhombohedral phase with a \(R3m\) space group due to its low PT content. However, careful analysis of the high-resolution synchrotron XRD data shown in Figs. 4(a)–4(d) reveals a multi-peak characteristic for the pseudocubic \(\{200\}_{pc}\) diffraction peak within the diffraction angle of 11.68°–11.80°. Thus, the obtained XRD pattern cannot be satisfied by the single \(R3m\) space group since \(R3m\) only allows for one \(\{200\}_{pc}\) peak, and there must be a low-symmetry phase contributing to the \(\{200\}_{pc}\) peak splitting. As expected, the high \(R_p\) value of 11.74% from the refinement results reveals that a single \(R3m\) model cannot accurately describe the measured data (Fig. S6 in the supplementary material).

Then, two mix-phase models, \(R3m+Pm\) (\(R+M_2\)) and \(R3m+Cm\) (\(R+M_4\)), were considered. We found that the fitting quality of the refinement using \(R3m+Pm\) set [Figs. 4(a) and 4(c)] is superior to \(R3m+Cm\) (Figs. S7 and S8 in the supplementary material), as confirmed by the relatively small \(R_p\) (7.67% for PINMT27 and 7.38% for PINMT30), where considerable monoclinic phase fractions of 57% and 74% were found in PINMT27 and PINMT30, respectively. Although the raw data could be better fitted by two monoclinic phases (\(Pm+\tilde{C}m\)) due to the larger number of the refined structural parameters, we still believe that the \(R3m+Pm\) model is the most accurate set representing the real material structure of PINMT27 and PINMT30 for the following two reasons: (i) These two compositions are located at the rhombohedral-rich MPB side. Thus, the \(R3m\) space group should not be completely ignored; (ii) \(Pm\) belongs to a monoclinic phase, which is essential for providing the polarization rotation path according to Landau free-energy theory.59,15–17 Therefore, we demonstrate that two phases with competing symmetries coexist in ternary
PIN-PMN-PT with relative low PT content. Such a characteristic is significantly different from the binary PMN-PT system, in which the pure $R_3m$ symmetry was confirmed in 0.72PMN-0.28PT by using the same synchrotron facility. A similar analysis strategy was also employed on the high-PT composition crystal, PINMT36. Considering the fact that it is located on the tetragonal-rich MPB side, the $P4mm$ space group cannot be ruled out. However, a simple, pure phase model with $P4mm$ cannot satisfy the XRD patterns shown in Figs. 4(g) and 4(h). $P4mm$ only allows a single peak of (200) and a single peak of (002), however, in Fig. 4(h) at least two Bragg reflections are obviously identified for (200)$_{\text{pc}}$ (2 theta $\sim$11.81°) and an asymmetric peak profile was found for (002)$_{\text{pc}}$ (2 theta of 11.60°–11.65°). From the Rietveld refinement [Figs. 4(b) and S12], Pm ($M_c$) is suggested to be in the secondary low-symmetry-phase rather than Cm ($M_a$), which is similar to the condition of PINMT27 and PINMT30, and consistent with the binary PMN-PT system with MPB composition. For the intermediate composition PINMT32, more complicated diffraction patterns with a broader profile were observed [Figs. 4(e) and 4(f)]. From a detailed analysis of the peak positions and intensities of the fitted profiles, none of the two-phase models (such as $P4mm + Cm$, $P4mm + Pm$, and even two monoclinic $Pm + Cm$) were found to fit well for the observed.
features (Figs. S9–S11 in the supplementary material). Thus, the three-phase model \( Pm + Cm + P4 mm \) offers a realistic solution [Fig. 4(f)], as supported by the significantly small \( R_p \) value of 6.19%.

Based on the above analysis, phase coexistence is revealed in all studied samples. Considering that the MPB of the relaxor-PT system is characterized by multi-phase features with complex phase behavior, such as expanded composition-span in PIN-PMN-PT strongly suggests a diffused MPB characteristic. It should be noted that the phase coexistence in the ternary relaxor-PT is an intrinsic feature of chemically complex systems, which is in good agreement with the observations in PMN-PT and PZT systems. Such a phase coexistence in relaxor-based ferroelectrics cannot be explained by the long-range compositional fluctuations since the phase stability can be disturbed by local PNRs. Note that the MPB in ferroelectrics is associated with random fields, compositional heterogeneity, polar nonegions, mesostructural heterogeneity, and nanodomains. In this context, the diffused MPB can be regarded as a MPB with local structural heterogeneity, which is more favorable in ternary PIN-PMN-PT than binary PMN-PT. Therefore, from a microstructure viewpoint, we can also understand why MPB occurs more easily in PIN-PMN-PT.

D. Phase diagram, improved thermal stability, and high piezoelectricity

To further explore the properties of the ternary PIN-PMN-PT crystals with MPB compositions, we collected the XRD patterns as a function of temperature from 100 to 600 K, and conducted the detailed fitting procedures. Figures 5(a)–5(d) show the temperature-driven structural evolutions and phase fractions for PINMT27, PINMT30, PINMT32, and PINMT36, respectively. For PINMT27 and PINMT30, the room-temperature phase of \( R1 + M_{C2} \) was suitable at low temperature down to 100 K and persisted up to 405 K (for PINMT27) and 375 K (for PINMT30), at which the two phases merged to a single \( M_{C2} \), followed by \( M_{C2} \rightarrow \) Cubic (space group: \( Pm3m \)) phase transitions occurring at 424 and 444 K, respectively. A similar phase transition sequence (two ferroelectric phases \( \rightarrow \) single ferroelectric phase \( \rightarrow \) paraelectric cubic phase) was also observed in PINMT36, in which \( T + M_{C2} \) merged to T at 483 K and finally transformed to a cubic phase at 496 K. More complicated ferroelectric phase transitions upon heating PINMT32 were further resolved, which followed \( M_{A1} + M_{C2} + T \rightarrow M_{C2} + T \), and finally to the cubic phase. Detailed temperature-dependent structural parameters of all studied samples are summarized in Figs. S13–S20 in the supplementary material.

According to the results of the phase evolutions shown in Figs. 5(a)–5(d), we re-plotted the composition-temperature phase diagram of the PIN-PMN-PT ternary system. The various monoclinic phases clearly diffuse into the R and T regions. Consequently, as shown in Fig. 5(e), MPB is not a narrow compositional region containing low-symmetry phase(s) (3%–5% for PMN-PT; 2% for PZN-PT), but an extremely broad MPB region covering at least 9% PT contents, namely, a "diffused MPB." Here, the term "diffused" means low-symmetry monoclinic phase significantly expands into the R and T phase regions, being distinct from the \( Pb(Zn_{0.52}Ti_{0.48})O_3 \)-BaTiO\(_3\), \( Pb(Zn_{0.52}Nb_{0.48})O_3 \)-BaTiO\(_3\), \( Pb(Zn_{0.7}Nb_{0.3})O_3 \)-BaTiO\(_3\), and \( Bi(Mg_{0.5}W_{0.5})O_3 \)-BaTiO\(_3\) systems, in which there is no low-symmetry phase observed and/or only narrow MPBs were reported. Such a broad composition region with co-existing phases indicates a strong competition among various ferroelectric phases with different polarization vectors.

The diffusion of monoclinic symmetry in PIN-PMN-PT can also be understood from a system energy perspective and confirmed by implementing first-principle calculations with long-range force considerations. We employed 0.26PIN-0.49PMN-0.25PT and 0.75PMN-0.25PT as an example pair to compare the energy of the low-symmetry phase and parent ferroelectric phase. As shown in Fig. 5(f), the enthalpy per unit volume of \( R3m \) is obviously lower than that of \( Pm \) in PMN-PT, while for PIN-PMN-PT, the enthalpy values of two symmetries are similar and the energy of \( Pm \) is even lower, which agrees well with our experimental results.

PIN-PMN-PT has a higher Curie temperature than its binary PMN-PT counterpart, and better thermal stability of structure/functionality can be expected, which can be explored from the aspect of the Landau-Ginzburg-Devonshire (LGD) theory and temperature-driven variation of the order parameters. From LGD theory on phase transition, the free energy of the system can be expanded in a power series of the order parameter \( \phi \):

\[
F = F_0 + \sum_{n=1}^{\infty} \frac{1}{n!} \phi^n.
\]

Here, \( \phi \) is a nonzero value below a critical point and zero for the high-symmetry phase. For the monoclinic phase, \( \beta = 90^\circ \) (\( \beta \) is the monoclinic angle, namely, the angle between lattice \( a \) and lattice \( c \)) can be used as order parameters, allowing the free energy to be expanded. Figure 5(g) compares the temperature-driven evolutions of \( \beta = 90^\circ \) in the PIN-PMN-PT and PMN-PT systems with different monoclinic phases. A more drastic change in order parameter as a function of temperature was observed in PMN-PT compared to PIN-PMN-PT. Thus, PIN-PMN-PT exhibits improved phase thermal stability. Consequently, the variation in the free energy profile of PIN-PMN-PT as a function of temperature should be much less than those of the PMN-PT systems. Considering the fact that the properties of perovskite ferroelectrics are strongly associated with the polarization variation and flatness of the potential wells described by their free-energy profile, high thermal stability of functionality can be expected in a PIN-PMN-PT system.

Figures 5(h) and 5(i) show the temperature dependence of variations in lateral electromechanical coupling factors \( k_{31} \) and piezoelectric coefficients \( d_{33} \) for PIN-PMN-PT and PMN-PT crystals, respectively. We observed that \( k_{31} \) maintained the same values with increasing temperature for PIN-PMN-PT up to 400 K, above which it decreased sharply due to the partial depolarization, which is 30 K higher than PMN-PT. Meanwhile the piezoelectric coefficients \( d_{33} \) of PIN-PMN-PT and PMN-PT were found to increase with increasing temperature and reach maxima at respective depolarization temperatures, above which they decrease significantly. It is noteworthy that PIN-PMN-PT has greater thermal stability in \( d_{33} \), which is evidenced by the slow increasing slope and higher depolarization temperature. As shown in Fig. 5(i), for PIN-PMN-PT crystals, the piezoelectric variation is ~70%–90% over the temperature range of 273–373 K, much less compared to its binary counterpart \( Pb(Mg_{0.33}Nb_{0.67})O_3 \)-\( PbTiO_3 \) where large piezoelectric variation, ~200%, is evidenced over the same temperature range.

Of particular importance is the improved thermal stability in the ternary PIN-PMN-PT system is not at the cost of decreased piezoelectric properties, from which a mechanism on the diffused MPB is proposed and shown schematically in Fig. 6. On the one hand, due to the presence of low-symmetry phase over a broader composition range in PIN-PMN-PT, the free energy profile becomes flatter than...
PMN-PT, yielding easier dipole variations such as polarization rotation/elongation under external electric field, where the competition between co-existing ferroelectric phases is responsible for the ultrahigh piezoelectricity [Fig. 6(a)]. On the other hand, considering the higher Curie temperature of PIN-PMN-PT, it has a more stable thermal status than PMN-PT at room temperature [Fig. 6(b)], accounting for the inferior piezoelectric activity but improved thermal stability, which generally occurs in most ferroelectric solid solution system as suggested in Fig. 1.

As shown in Fig. 5(g), for an individual phase in PIN-PMN-PT, the improved thermal stability of phase can be confirmed by temperature dependence of order parameter, nevertheless the energy gap between various ferroelectric phases at a given temperature is smaller than PMN-PT as seen in Figs. 5(a)–5(f). Therefore, considering these two opposite effects, PIN-PMN-PT exhibit the net result of improved thermal stability while possessing almost the same room temperature piezoelectric activity as PMN-PT, as schematically depicted in Fig. 6(c). At room temperature, PIN-PMN-PT is farther away from temperature-driven phase boundaries than PMN-PT, whereas has a diffused MPB characteristic. The former factor dominates improved thermal stability, and the latter make considerable contribution to piezoelectric activity.

III. CONCLUSION

We report the phase coexistence and the diffusion of the low-symmetry phase in ternary PIN-PMN-PT solid solutions, which are
responsible for the comparably high dielectric/piezoelectric properties compared to their binary PMN-PT counterparts, while possessing greatly improved thermal stability. The emergence of strong relaxor-like behavior results in intense interaction between the PNRs and acoustic waves, accounting for symmetry breaking. We also re-plotted the composition-temperature phase diagram of PIN-PMN-PT, which is crucial for materials engineering of this complicated system. These results inspire us to induce additional structural heterogeneity for expanding the phase coexistence region to achieve high piezoelectricity, meanwhile the endmember with elevated Curie temperature in the solid solution system is expected to play a positive role in the property thermal stability. The compensated piezoelectricity contributed by diffused MPB is highlighted by the pink area. Considering the fact that the piezoelectric property is strongly associated with the composition in relaxor-PT solid solutions, in the discussion of Fig. 6, the PMN-PT and PIN-PMN-PT have the same PT contents, where the comparable room temperature piezoelectric coefficients can be observed.

IV. EXPERIMENTAL SECTION

A. Crystal growth and sample preparation

The PIN-PMN-PT crystals were grown by a modified Bridgman method at TRS Technologies (State College, PA, USA). Real-time Laue x-ray back diffractions with an accuracy of 0.5° were employed to determine the orientations of the samples. The dimensions and aspect ratios of the piezoelectric resonator samples were specified by the IEEE standards of piezoelectricity.27 Vacuum-sputtered gold was applied to the faces of the samples as electrodes. The samples were poled along different crystallographic directions at room temperature with an electric field of 10–20 kV cm⁻¹ to form
stable engineered-domain configurations or at elevated temperatures under an electric field of 2–4 kV cm⁻¹ by field-cooling poling method to obtain single domain states.

B. Dielectric, piezoelectric, and electromechanical measurements

The temperature dependence of the dielectric permittivity was measured using an LCR meter (HP4980) connected to a computer-controlled temperature chamber. A home-made temperature controller and Model 325 Cryogenic Temperature Controller (Lake Shore Cryotronics) were employed for high- and low-temperature tests, respectively. The piezoelectric coefficients were determined by the resonance method, following the IEEE standard on piezoelectricity. The electric-field-induced strain was determined using a linear variable differential transducer driven by a lock-in amplifier (Stanford Research System, Model SR830). The resonance and anti-resonance frequencies of the resonator were measured by an HP4294A impedance-phase gain analyzer. Then, the values of electromechanical coupling factors were derived, and mechanical quality factors were obtained using the 3-dB method.

C. Synchrotron-based structure characterizations

Before conducting structural characterizations, the samples were annealed at 800 °C for 24 hours and then slowly cooled down to room temperature to remove the residual stress in the lattice. Synchrotron sub-micron x-ray fluorescence measurements were conducted at beamline 21-D-D, Advanced Photon Source (APS), Argonne National Laboratory (ANL), with source energy of 20 keV with a beam size of 0.2 μm (H) × 0.2 μm (V). Then, the quantitative compositions of various samples were determined by elemental analysis. Synchrotron x-ray diffraction experiments were then performed at beamline 11-BM, APS, ANL, from 100 to 600 K. The wavelength is 0.414212 Å, and the instrument resolution (Ad/d) was 0.00017, representing a state-of-the-art d-spacing resolution for diffraction measurements worldwide. Rietveld refinements of XRD data were performed using the General Structure Analysis Structure program.

D. First-principles simulation

We implemented a first-principle calculation to compare the phase energies of PMN-PT and PIN-PMN-PT over their compositional diagrams. The calculations were performed under the framework of density functional theory by the Vienna ab initio simulation package. The electron-ion interactions of all atoms were approximated using a projector augmented wave scheme. The exchange-correlation functional was described by the generalized gradient approximation in the Perdew-Burke-Ernzerhof parameterization optimized for bulk solids. We also corrected the term of van der Waals force through a DF2 method and calculated long distance interactions up to 60 Å. Our calculation employed a 2 × 2 × 2 supercell with a total number of 24 available cations on the B sites of ABO₃ perovskite. For the specific composition of 0.75PMN-0.25PT and the indium incorporated 0.26PIN-0.49PMN-0.25PT, the numbers of B-site cations are approximated in Table S2 in the supplementary material. The cell variables, volume, and atomic positions were allowed to relax to optimize interatomic forces below 0.01 eV/Å. Since the unit cell of all three phases (P4mm, Pm, and R3m space groups) can be regarded as minor distortion on a cubic system, we simplified to treat the three cell edges throughout our simulation equally. Another challenge is the mixing of cations in a single unit cell, which was considered: A-type with Ti/(Nb,Mg) atoms alternatively forming along the c-axis and G-type with Ti/(Nb,Mg) aligned along the (110) plane. Our calculation showed that the A-type ordering yields lower total energy. For the indium-incorporated system, 3 indium atoms replaced 1 niobium and 2 magnesium atoms, and we tried various combinations. The structure with the lowest energy was used for data analysis. The supercells used for PMN-0.25PT and PIN-PMN-0.25PT in the simulation are given in Figs. S21 and S22.

SUPPLEMENTARY MATERIAL

See supplementary material for detailed characterizations on structure and property of various relaxor-PT crystals (Figs. S1–S22, Tables S1–S2).

ACKNOWLEDGMENTS

Gang Liu would like to acknowledge the support from NSAF (Grant No. U19130401). Qingyang Hu is supported by NSFC (Grant No. 17N1051-0213). Structure characterizations were performed at beamline 2-ID-D and beamline 11-BM at APS, Argonne National Laboratory (ANL). The use of APS facilities was supported by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences (DEAC02-06CH11357). We thank Dr. Wesley Hackenberger and Dr. Jun Luo from TRS Technologies (State College, PA) for providing high-quality relaxor-PT single crystals. We especially thank Dr. Ho-kwang Mao for useful discussions. We appreciate Ms. Freyja O’Toole for her language assistance.

REFERENCES


